

Schottky Power Diode, 35A

Features

- Fast Switching
- Low forward voltage drop
- High surge capability
- High efficiency, low power loss
- Normal and Reverse polarity



DO-203AA (DO-4)

Maximum Ratings ($T_J = 25^\circ\text{C}$, unless otherwise noted)

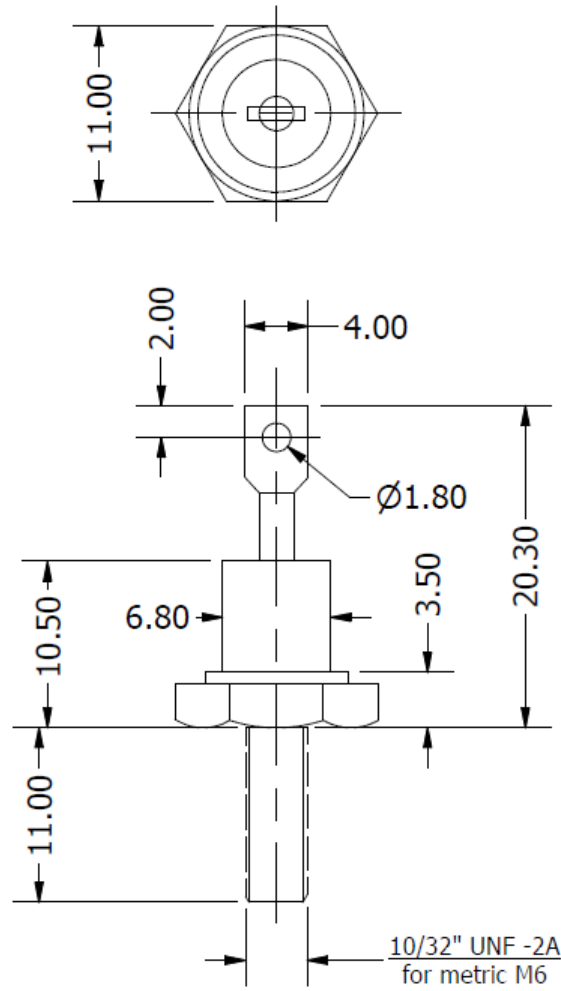
Parameter	Test Conditions	Symbol	MBR3545(R)	MBR3560(R)	MBR3580(R)	MBR35100(R)	Unit
Repetitive peak reverse voltage		V_{RRM}	45	60	80	100	V
RMS reverse voltage		V_{RMS}	32	42	57	70	V
DC blocking voltage		V_{DC}	45	60	80	100	V
Continuous forward current	$T_C \leq 110^\circ\text{C}$	I_F	35	35	35	35	A
Surge non-repetitive forward current, half-sine wave	$T_C = 25^\circ\text{C}$	I_{FSM}	600	600	600	600	A
Forward voltage	$I_F = 35\text{ A}$ $T_J = 25^\circ\text{C}$	V_F	0.68	0.75	0.84	0.84	V
Reverse current	$V_R = 20\text{V}$, $T_J = 25^\circ\text{C}$	I_R	1.5	1.5	1.5	1.5	mA
	$V_R = 20\text{V}$, $T_J = 125^\circ\text{C}$		25	25	25	25	

Thermal & Mechanical Specifications ($T_J = 25^\circ\text{C}$, unless otherwise noted)

Parameters	Symbol	MBR3545(R)	MBR3560(R)	MBR3580(R)	MBR35100(R)	Unit
Maximum thermal resistance, junction to case	$R_{th(jc)}$	1.5				$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J	-55 to 150				$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 175				$^\circ\text{C}$
Mounting torque (non-lubricated threads)	F	2.0				Nm
Approximate allowable weight	W	5.0				g



Package Outline



ALL DIMENSIONS IN MM